



GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER MODULE, 32 - 46 GHz OUTPUT

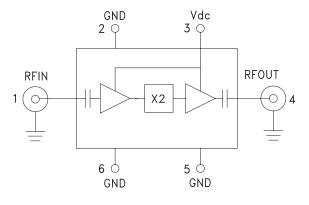


Typical Applications

The HMC-C034 is suitable for:

- Clock Generation Applications: SOWET OC-192 & SDH STM-64
- Point-to-Point & VSAT Radios
- Test Instrumentation
- Military EW/Radar
- Space

Functional Diagram



Features

High Output Power: +13 dBm

Low Input Power Drive: 0 to +6 dBm

100 KHz SSB Phase Noise: -130 dBc/Hz

Fo Isolation >30 dBc @ Fout = 38 GHz

Single Supply: +5V @ 70 mA

Hermetically Sealed Module

Field Replaceable 2.92mm Connectors

-55 °C to +85 °C Operating Temperature

General Description

The HMC-C034 is a x2 active broadband frequency multiplier utilizing GaAs PHEMT technology in a miniature hermetic module. When driven by a 3 dBm signal, the multiplier provides +13 dBm typical output power from 32 to 46 GHz. The Fo isolation is >30 dBc with respect to output signal level. This frequency multiplier features DC blocked I/O's, and is ideal for use in LO multiplier chains for Pt to Pt & VSAT Radios yielding reduced parts count vs. traditional approaches. The low additive SSB Phase Noise of -130 dBc/Hz at 100 kHz offset helps maintain good system noise performance.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vdc = +5V, 3 dBm Drive Level

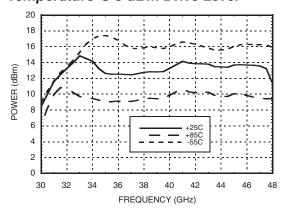
Parameter	Min.	Тур.	Max.	Units
Frequency Range, Input	16 - 23			GHz
Frequency Range, Output	32 - 46			GHz
Output Power	8	13		dBm
Fo Isolation (with respect to output level)		30		dBc
Input Return Loss		12		dB
Output Return Loss		8		dB
SSB Phase Noise (100 kHz Offset)		-130		dBc/Hz
Supply Current		70		mA



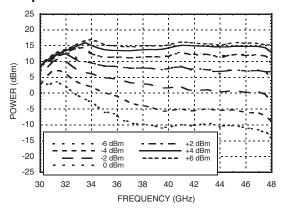


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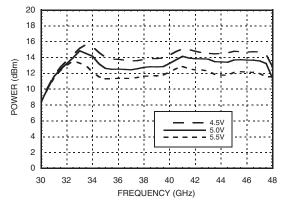
Output Power vs. Temperature @ 3 dBm Drive Level



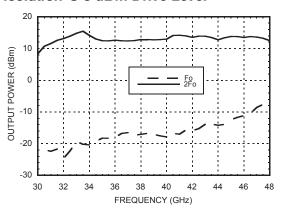
Output Power vs. Drive Level



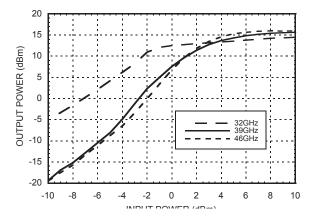
Output Power vs. Supply Voltage @ 3 dBm Drive Level



Isolation @ 3 dBm Drive Level



Output Power vs. Input Power

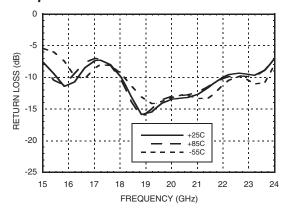




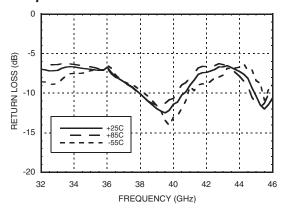


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Input Return Loss vs. Temperature @ 0 dBm Drive Level



Output Return Loss vs. Temperature @ 0 dBm Drive Level



Absolute Maximum Ratings

RF Input (Vdc = +5V)	+13 dBm	
Bias Supply Voltage (Vdc)	+6 Vdc	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-55 to +85 °C	

Typical Supply Current vs. Vdd

Vdd (Vdc)	Idd (mA)	
4.5	69	
5.0	70	
5.5	70	

Note:

Multiplier will operate over full voltage range shown above.



Pin Description

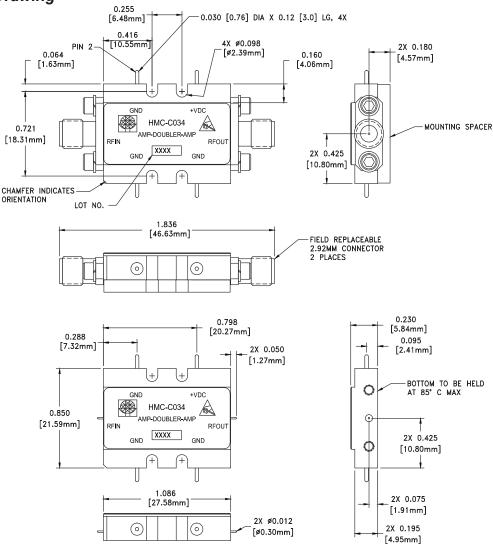
Pin Number	Function	Description	Interface Schematic
1	RFIN and RF Ground	Pin is AC coupled and matched to 50 Ohms. RFIN uses a female 2.92mm field replaceable connector.	RFINO— —
2, 5, 6	GND	One of these pins must be connected to power supply ground.	GND =
3	Vdc	Power supply voltage for the amplifier includes a 7.5V zener diode for over voltage and negative voltage protection	Vdc ○ 7.5V ↓ ↓ =
4	RFOUT and RF Ground	Pin is AC coupled and matched to 50 Ohms. RFOUT uses a female 2.92mm field replaceable connector.	→ → RFOUT





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Outline Drawing



VIEW SHOWN WITH CONNECTORS AND MOUNTING SPACER REMOVED

Package Information

Package Type	C-10	
Package Weight [1]	18.7 gms ^[2]	
Spacer Weight	3.3 gms ^[2]	

[1] Includes the connectors

[2] ±1 gms Tolerance

NOTES:

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR
- 2. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
- 3. MOUNTING SPACER: NICKEL PLATED ALUMINUM
- 4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 5. TOLERANCES: 0.010 [0.25] UNLESS OTHERWISE SPECIFIED